

Intraplanar couplings in the CuO_2 lattice of cuprate superconductors

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Abstract

We have investigated the doping dependencies of the basal areas in single-layer high- T_c cuprates $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ and $\text{HgBa}_2\text{CuO}_x$, as well as in two-layer $\text{Y}_{1-y}\text{Ca}_y\text{Ba}_2\text{Cu}_3\text{O}_x$ and $\text{HgBa}_2\text{CaCu}_2\text{O}_x$. The basal areas not only tend to shrink on hole doping, as expected from single electron quantum chemistry, but exhibit also a “bulge” around optimum doping. We attribute the “bulge” to the effects of the strongly correlated quantum liquid on the CuO_2 lattice, rendering it nearly incompressible around optimum doping, but highly compressible in the weakly overdoped regime. Inhomogenous doping cannot account for this anomaly in the electronic compressibility of the CuO_2 lattice.

Key words: lattice, strong correlations, electronic compressibility, $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$, $\text{HgBa}_2\text{CuO}_x$, $\text{YBa}_2\text{Cu}_3\text{O}_x$, $\text{HgBa}_2\text{CaCu}_2\text{O}_x$
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The detailed geometry and the dimensions of the Cu–O layers in the superconducting cuprates are controlled by extrinsic and intrinsic effects. The extrinsic effects arise mainly from the complex stereochemistry of the structural blocks outside the planes doping the holes into the Cu–O layers. Mixed valent cations, oxygen defects, disorder, structural misfit and strongly polarizing bonds induce various types of strain, displacing the copper and oxygen atoms in-plane and out-of-plane. The intrinsic effects are connected with the generic properties of the quantum liquid created by the hole doping into a Mott insulator [1]. In this short note we present experimental evidence for that the strong electron-electron correlations inherent in this quantum liquid affect significantly the area of the CuO_2 lattice.

Hole doping removes electrons from the antibonding $\sigma^*\text{Cu}3d_{x^2-y^2}\text{O}2p_{x,y}$ band, increases the amount of covalent character in the Cu–O bonds, and is thus expected to shorten them. Strain from the chemically complex extrinsic properties, in particular anisotropies, may however mask or even invert the expected shortening of the individual bond lengths, e.g. in $\text{YBa}_2\text{Cu}_3\text{O}_x$ where the a -axis contracts as the

b -axis expands on hole doping [1,2]. The basal area, B ,

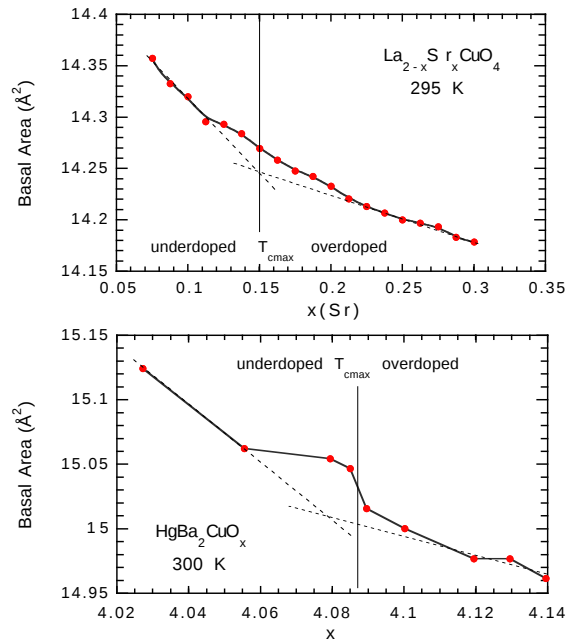


Fig. 1. Basal areas of one-layer cuprates as a function of doping.

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defined by the square of the basal Cu–Cu distances, turns out to be almost unaffected by externally driven changes of the crystal symmetry, and hence allows for comparisons between various systems with very different doping chemistries.

Fig. 1 displays as a function of doping the basal areas of the one-layer systems $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ ($T_{\text{cmax}} = 36$ K) [3] and $\text{HgBa}_2\text{CuO}_x$ ($T_{\text{cmax}} = 96$ K) [4], Fig. 2 of the two-layer systems $\text{Y}_{1-y}\text{Ca}_y\text{Ba}_2\text{Cu}_3\text{O}_x$ ($T_{\text{cmax}} = 92$ K) [2] and $\text{HgBa}_2\text{CaCu}_2\text{O}_x$ ($T_{\text{cmax}} = 127$ K) [4]. B is derived from the lattice parameters as reported by Radaelli *et al.* [3] (LSCO), Fukuoka *et al.* [4] (HBCO, HBCCO), and Kaldis *et al.* [2] (YBCO). The thick drawn out lines connecting the data points are a guide to the eye. The overall behavior of $B(x)$ exhibits surprisingly strong similarities in all systems under comparison: *i.* As expected from the increasing covalency with hole doping the basal areas shrink appreciably (by about 1%) between the insulator–metal transition and the strongly overdoped regime. *ii.* $B(x)$ exhibits a “bulge” around optimum doping. The “bulge” is weakest in $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ and strongest in $\text{HgBa}_2\text{CaCu}_2\text{O}_x$. The thin dashed straights are fitted to the data points at the strongly under- and overdoped ends and, extrapolated towards the underdoped-overdoped phase boundary, turn out to intersect around optimum doping, x_{opt} . We use them as rough approximations defining the single electron quantum chemical “background” $B_0(x)$. The change of slope around x_{opt} indicates that the Cu–O bonding changes from a nearly ionic character in the lightly doped regime to covalency in the strongly overdoped regime.

Thus the “bulge” may be seen to ride on the single electron quantum chemical background. We attribute it to the effect of strong electron-electron correlations on the CuO_2 lattice of the doped Mott insulator. Its basic physics may be described in terms of the competition between the magnetic exchange energy J and the kinetic energy per hole xt , underlying a no-double-occupant constraint. Here the doped holes appear as vacancies in the background of a spin singlet liquid in the CuO_2 lattice. The strong repulsive interaction set by $J \simeq 1500$ K is expected to render the underlying lattice almost incompressible, at least much less compressible than a liquid of noninteracting holes residing in the same grid. Defining a electronic compressibility by $\kappa_e \propto -\partial(B - B_0)/\partial\mu$, where the pressure exerted by the holes, $\mu \propto xt$, we find $\kappa_e \simeq 0$ close to optimum doping. Apparently the strongly correlated quantum liquid renders the lattice almost incompressible where T_c achieves its maximum.

The disappearance of the “bulge” in the weakly overdoped regime may be accompanied by a structural phase transformation of a martensitic type as recently reported for $\text{YBa}_2\text{Cu}_3\text{O}_x$ [5,1].

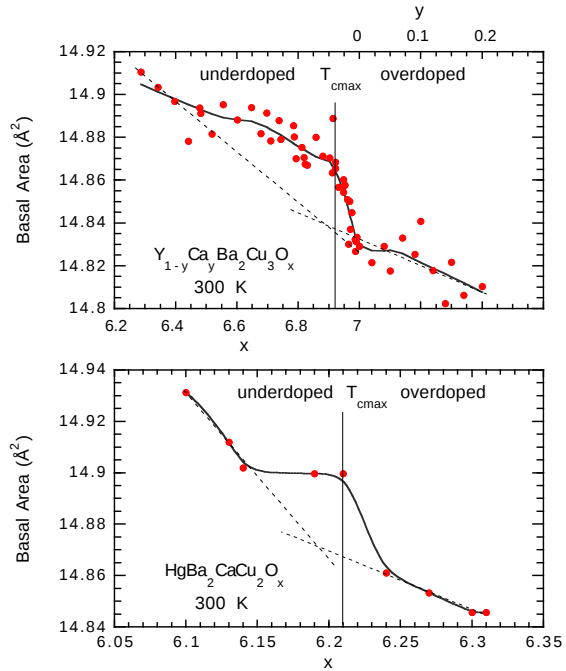


Fig. 2. Basal areas of two-layer cuprates as a function of doping.

We can however exclude that the “bulge” is connected with the formation of stripes or related nano-scale domains caused by inhomogeneous doping. First, $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$, due to its relatively high structural compliance [6] the system most susceptible to stable long range ordered stripes, exhibits the weakest “bulge”. Second, the Hg-cuprates, due to their almost flat CuO_2 lattices (zero structural compliance) almost unable to accommodate stripes, exhibit the strongest “bulges”. We conclude that homogeneous doping governs the doping dependence of the basal area.

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